

AMENDMENTS

In the Specification:

Amend the Title to read METHOD OF MANUFACTURING INSULATED GATE SEMICONDUCTOR DEVICE AND MANUFACTURING METHOD THEREOF.

On the first page, after the Title, insert as the first paragraph of the specification the following new paragraph.

Reference to Related Applications:

This application is a division of Serial No. 09/925,628, filed August 10, 2001, now U.S.

Patent No. _____